

BSP75G 60V self-protected low-side IntelliFET™ MOSFET switch

Summary

Continuous drain source voltage V_{DS} =60V On-state resistance 550m Ω

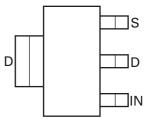
Nominal load current $1.4A (V_{IN} = 5V)$

Clamping energy 550mJ



Description

Self-protected low side MOSFET. Monolithic over temperature, over current, over voltage (active clamp) and ESD protected logic level power MOSFET intended as a general purpose switch.



Features

- Short circuit protection with auto restart
- Over-voltage protection (active clamp)
- Thermal shutdown with auto restart
- Over-current protection
- Input protection (ESD)
- · High continuous current rating
- · Load dump protection (actively protects load)
- Logic level input

Ordering information

| Device | Reel size (inches) | Tape width (mm) | Quantity per reel | |
|----------|-----------------------|--------------------|-------------------|--|
| BSP75GTA | 7 | 12mm embossed | 1,000 | |
| BSP75GTC | 13 | 12mm embossed | 4,000 | |

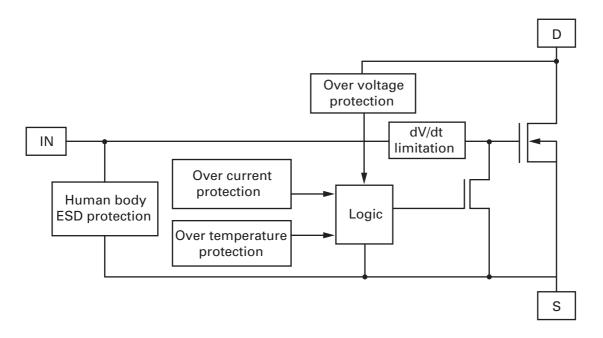
Device marking

BSP75G

Note:

The tab is connected to the drain pin, and must be electrically isolated from the source pin. Connection of significant copper to the tab is recommended for best thermal performance.

Functional block diagram



Applications

- · Especially suited for loads with a high in-rush current such as lamps and motors.
- All types of resistive, inductive and capacitive loads in switching applications.
- μC compatible power switch for 12V and 24V DC applications.
- Automotive rated.
- · Replaces electromechanical relays and discrete circuits.
- Linear mode capability the current-limiting protection circuitry is designed to de-activate at low Vds, in order not to compromise the load current during normal operation. The design maximum DC operating current is therefore determined by the thermal capability of the package/board combination, rather than by the protection circuitry.

Absolute maximum ratings

| Parameter | Symbol | Limit | Unit |
|--|---------------------|-------------|------|
| Continuous drain-source voltage | V _{DS} | 60 | V |
| Drain-source voltage for short circuit protection | V _{DS(SC)} | 36 | V |
| Continuous input voltage | V _{IN} | -0.2 +10 | V |
| Peak input voltage | V _{IN} | -0.2 +20 | V |
| Operating temperature range | T _j , | -40 to +150 | °C |
| Storage temperature range | T _{stg} | -55 to +150 | °C |
| Power dissipation at T _A =25°C ^(a) | P _D | 2.5 | W |
| Continuous drain current @ V _{IN} =10V; T _A =25°C ^(a) | I _D | 1.6 | Α |
| Continuous drain current @ V _{IN} =5V; T _A =25°C ^(a) | I _D | 1.4 | Α |
| Pulsed drain current @ V _{IN} =10V | I _{DM} | 5 | А |
| Continuous source current (body diode) ^(a) | I _S | 3 | Α |
| Pulsed source current (body diode) | I _S | 5 | Α |
| Unclamped single pulse inductive energy | E _{AS} | 550 | mJ |
| Load dump protection | $V_{LoadDump}$ | 80 | V |
| Electrostatic discharge (human body model) | V _{ESD} | 4000 | V |
| DIN humidity category, DIN 40 040 | | E | |
| IEC climatic category, DIN IEC 68-1 | | 40/150/56 | |

Thermal resistance

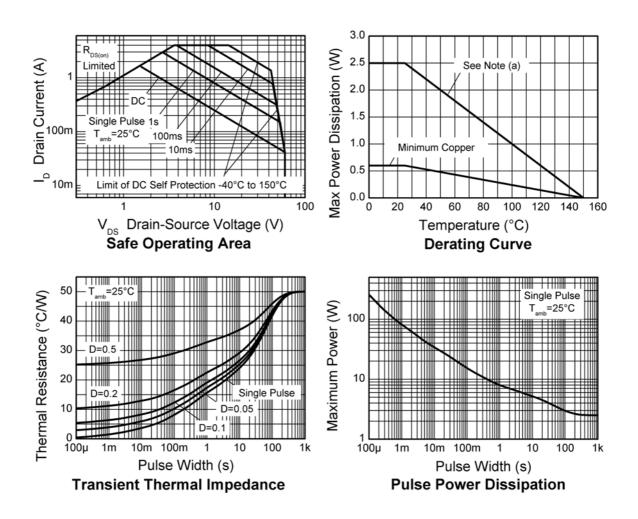
| Parameter | Symbol | Limit | Unit | |
|------------------------------------|-----------------|-------|------|--|
| Junction to ambient ^(a) | $R_{\Theta JA}$ | 50 | °C/W | |
| Junction to ambient ^(b) | $R_{\Theta JA}$ | 24 | °C/W | |
| Junction to ambient ^(c) | $R_{\Theta JA}$ | 208 | °C/W | |

NOTES:

⁽a) For a device surface mounted on 37mm x 37mm x 1.6mm FR4 board with a high coverage of single sided 2oz weight copper.
(b) For a device surface mounted on FR4 board and measured at t<=10s.

⁽c) For a device mounted on FR4 board with the minimum copper required for electrical connections.

Characteristics



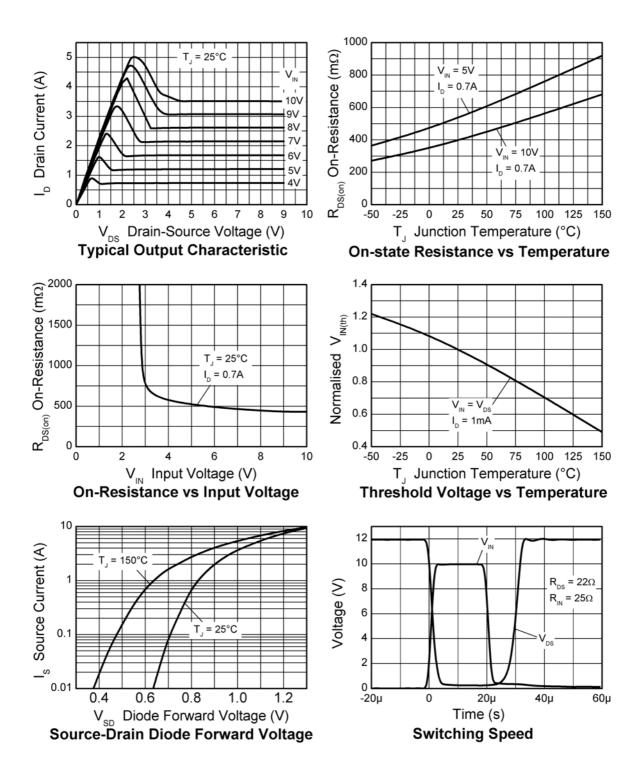
Electrical characteristics (at Tamb = 25°C unless otherwise stated)

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions |
|--|-------------------------------------|------|------|------|------|---|
| Static characteristics | | 1 | | 1 | | |
| Drain-source clamp voltage | V _{DS(AZ)} | 60 | 70 | 75 | V | I _D =10mA |
| Off-state drain current | I _{DSS} | | 0.1 | 3 | μΑ | V _{DS} =12V, V _{IN} =0V |
| Off-state drain current | I _{DSS} | | 3 | 15 | μΑ | V _{DS} =32V, V _{IN} =0V |
| Input threshold voltage (*) | V _{IN(th)} | 1 | 2.1 | | V | V _{DS} =V _{GS} , I _D =1mA |
| Input current | I _{IN} | | 0.7 | 1.2 | mA | V _{IN} =+5V |
| Input current | I _{IN} | | 1.5 | 2.7 | mA | V _{IN} =+7V |
| Input current | I _{IN} | | 4 | 7 | mA | V _{IN} =+10V |
| Static drain-source on-state resistance | R _{DS(on)} | | 520 | 675 | mΩ | V _{IN} =+5V, I _D =0.7A |
| Static drain-source on-state resistance | R _{DS(on)} | | 385 | 550 | mΩ | V _{IN} =+10V, I _D =0.7A |
| Current limit ^(†) | $I_{D(LIM)}$ | 0.7 | 1.1 | 1.75 | Α | $V_{IN}=+5V$, $V_{DS}>5V$ |
| Current limit ^(†) | I _{D(LIM)} | 2 | 3 | 4 | Α | V_{IN} =+10V, V_{DS} >5V |
| Dynamic characteristics | | | | | | |
| Turn-on time (V _{IN} to 90% I _D) | t _{on} | | 2.2 | 10 | μS | $R_L=22\Omega$, $V_{DD}=12V$, $V_{IN}=0$ to +10V |
| Turn-off time (V _{IN} to 90% I _D) | t _{off} | | 13 | 20 | μS | R _L =22Ω, V _{DD} =12V, V _{IN} =+10V to 0V |
| Slew rate on (70 to 50% V _{DD}) | -dV _{DS} /dt _{on} | | 10 | 20 | V/μs | $R_L=22\Omega$, $V_{DD}=12V$, $V_{IN}=0$ to +10V |
| Slew rate off (50 to 70% V _{DD}) | dV _{DS} /dt _{off} | | 3.2 | 10 | V/μs | $R_L=22\Omega$, $V_{DD}=12V$, $V_{IN}=+10V$ to $0V$ |
| Protection functions (‡) | | | | | | |
| Required input voltage for over temperature protection | V _{PROT} | 4.5 | | | V | |
| Thermal overload trip temperature | T _{JT} | 150 | 175 | | °C | |
| Thermal hysteresis | | | 10 | | °C | |
| Unclamped single pulse inductive energy Tj=25°C | E _{AS} | 550 | | | mJ | I _{D(ISO)} =0.7A, V _{DD} =32V |
| Unclamped single pulse inductive energy Tj=150°C | E _{AS} | 200 | | | mJ | I _{D(ISO)} =0.7A, V _{DD} =32V |
| Inverse diode | | | | | | |
| Source drain voltage | V_{SD} | | | | 1 | V _{IN} =0V, -I _D =1.4A |

^(*) Protection features may operate outside spec for V_{IN} <4.5V. (†) The drain current is limited to a reduced value when V_{DS} exceeds a safe level.

^(‡) Integrated protection functions are designed to prevent IC destruction under fault conditions described in the datasheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous, repetitive operation.

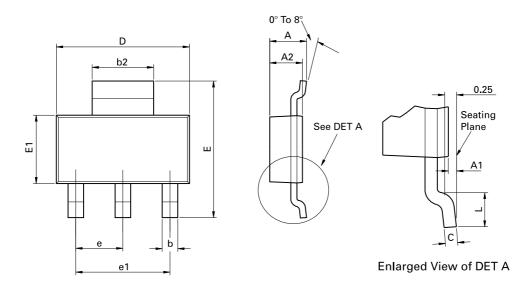
Characteristics



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Package outline - SOT223



Conforms to JEDEC TO-261 AA Issue B

| Dim. | Millin | neters | Inc | hes | Dim. | Millimeters | | Inches | |
|------|--------|--------|--------|-------|------|-------------|------|------------|-------|
| | Min. | Max. | Min. | Max. | | Min. | Max. | Min. | Max. |
| Α | - | 1.80 | - | 0.071 | е | 2.30 BSC | | 0.0905 BSC | |
| A1 | 0.02 | 0.10 | 0.0008 | 0.004 | e1 | 4.60 BSC | | 0.181 BSC | |
| b | 0.66 | 0.84 | 0.026 | 0.033 | E | 6.70 | 7.30 | 0.264 | 0.287 |
| b2 | 2.90 | 3.10 | 0.114 | 0.122 | E1 | 3.30 | 3.70 | 0.130 | 0.146 |
| С | 0.23 | 0.33 | 0.009 | 0.013 | L | 0.90 | - | 0.355 | - |
| D | 6.30 | 6.70 | 0.248 | 0.264 | - | - | - | - | - |

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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